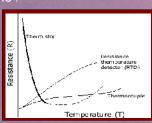


# The Effect Of SiO<sub>2</sub> Addition On The Characteristics Of CuFe<sub>2</sub>O<sub>4</sub> Ceramics For NTC

Wiendartun<sup>1)</sup> & Dani Gustaman Syarif<sup>2)</sup>
1) Departement Of Physics, UPI, Bandung.
2) Nuclear Technology Center for Materials and Radiometry – BATAN, Bandung.

## INTRODUCTION

- THERMISTOR → Thermally Sensitive Resistor.
- NTC CHARACTERISTIC :



PRODUCT EXAMPLES:





- Important electronic component.
  - Sectors: Biomedical, aerospace, instrumentation, communications, automotive
- and HVACI Heating, Ventilation, Air conditioning and Refrigeration).

   Application: Temperature measurement, circuit compensation, suppression of in rush-current, flow rate sensor and pressure sensor.
- Most, thermistors are produced from spinel ceramics based on transition metal
- oxides forming general formula AB<sub>2</sub>O<sub>4</sub>.

   Need alternative (Expecially based on abundant material (mineral) in Indonesia)

  → CuFe<sub>2</sub>O<sub>4</sub> is proposed, including that added with SiO<sub>2</sub>.
- Predicted that the SiO<sub>2</sub> addition can improve the characteristics ceramic for NTC thermistors of the CuFe<sub>2</sub>O<sub>4</sub>











CRUSHING

3, 9 ton/Cm2

PRESSING

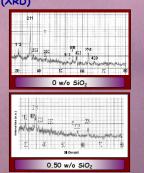
1100 °C/2 h SINTERING

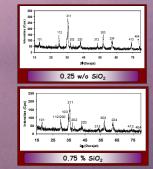
CHARACTERIZATION

- > XRD
- Electrical

Microstructural

## RESULT (XRD)



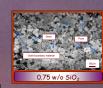


XRD profiles of CuFe<sub>2</sub>O<sub>4</sub> based-ceramics

# **RESULTS** (Microstructure)







Microstructure of the CuFe<sub>2</sub>O<sub>4</sub> based-ceramics

| In Rosistivity list ik, p (in Ohm-cm) | 9 -<br>8 -<br>7 -<br>6 -<br>5 -<br>4 -<br>3 - | CONTRACTOR OF THE PARTY OF THE | + 0 w/o SiO2<br>ID 0.25 w/o SiO2<br>- 0.50 w/o SiO2<br>0.75 w/o SiO2 |
|---------------------------------------|---|---|--|
|                                       | 0.0025  | 0.003   | 0.0035   |
|                                       |   | 1/T (1/*K)  |  |

|     | (w/o) | ( K) | (%/ K) | (Ohm-Cm |  |  |
|-----|-------|------|--------|---------|--|--|
| 1.  | 0.00  | 2548 | 2.83   | 291     |  |  |
| 2.  | 0.25  | 2358 | 2.62   | 1079    |  |  |
| 3.  | 0.50  | 2884 | 3.20   | 4788    |  |  |
| 4.  | 0.75  | 3308 | 3.68   | 9400    |  |  |
| W 1 |       |      |        |         |  |  |

Ln resistivity (p) vs 1/T of SiO<sub>2</sub> added- CuFe<sub>2</sub>O<sub>4</sub> ceramics

rket requirement for B  $\geq$  2000 oK and  $\alpha \geq$  2.2 % Market requirement for pRT = 10 ohm.cm -1 Mohm.cm

- NTC Thermistor

- BetaTHERM Sensors [on line]. Available: http://www.betatherm.com.
- Eun Sang Na, Un Gyu paik, Sung Churl Choi, "The effect of a microstructure on the electrical properties of a Mn-Co-Ni-O th Journal of Ceramic Processing Research, Vol.2, No. 1, pp 31
- Miendartun, Dani Gustaman Syarif. The Effect of TiO2 Addition racteristics of Sciences (ICMNS) 2006, ITB, Bandung, October 2

The authors wish to acknowledge their deep gratitude to DIKTI, Department of National Education of Indonesian Government for financial support under h Pekerti program with contract No.014/SPP/PP/DP2M/II/2006a